

AS358/358A/358B

LOW POWER DUAL OPERATIONAL AMPLIFIERS

Description

The AS358/358A/358B consists of two independent, high gain and internally frequency compensated operational amplifiers, they are specifically designed to operate from a single power supply. Operation from split power supply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltages. Typical applications include transducer amplifiers, DC gain blocks and most conventional operational amplifier circuits.

The AS358/358A/358B series is compatible with industry standard 358. The AS358A has more stringent input offset voltage than the AS358.

The AS358 is available in PDIP-8, TDIP-8, SO-8, TSSOP-8 and MSOP-8 packages, the AS358A is available in PDIP-8 and SO-8 packages and AS358B is available in TSSOP-8 package.

Features

- Internally Frequency Compensated for Unity Gain
- Large Voltage Gain: 100dB (Typical)
- Low Input Bias Current: 20nA (Typical)
- Low Input Offset Voltage: 2mV (Typical)
- Low Supply Current: 0.5mA (Typical)
- Wide Power Supply Voltage:
 - Single Supply: 3V to 36V
 - Dual Supplies: ±1.5V to ±18V
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V to V_{cc} -1.5V
- Lead-Free Packages: SO-8, PDIP-8 and TSSOP-8
 - Totally Lead-Free; RoHS Compliant (Notes 1 & 2)
- Lead-Free Packages, Available in "Green" Molding Compound: SO-8, PDIP-8, TDIP-8, TSSOP-8 and MSOP-8
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



(PDIP-8/TDIP-8)

Applications

- Battery Charger
- Cordless Telephone
- Switching Power Supply

Antimony Free. "Gr



Typical Applications Circuit



Battery Charger





Power Amplifier

DC Summing Amplifier



Typical Applications Circuit (Cont.)





AC Coupled Non-Inverting Amplifier

 $\begin{array}{c} R1 & 1M \\ \hline \\ 0.001 \mu F \\ \hline \\ R2 & 100k \\ \hline \\ R3 & 100k \\ \hline \\ R5 & 100k \\ \hline \\ R4 \\ 100k \\ \hline \\ \end{array}$

Pulse Generator





DC Coupled Low-Pass Active Filter



Functional Block Diagram



Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Parameter	Rati	Unit	
V _{CC}	Power Supply Voltage	40		V
V _{ID}	Differential Input Voltage	40		V
V _{IC}	Input Voltage	-0.3 to 40		V
		PDIP-8	830	
_		SO-8	550	
PD	Power Dissipation ($T_A = +25^{\circ}C$)	TSSOP-8	500	mW
		MSOP-8	470	
TJ	Operating Junction Temperature	Operating Junction Temperature +150		°C
T _{STG}	Storage Temperature Range	berature Range -65 to +150		°C
T _{LEAD}	Lead Temperature (Soldering, 10 Seconds)	rre (Soldering, 10 Seconds) +260		°C

Notes: 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

5. ESD sensitivity.

Recommended Operating Conditions

Symbol	Parameter	Min	Мах	Unit
V _{CC}	Supply Voltage	3	36	V
T _A	Ambient Operating Temperature Range	-40	+85	°C



Electrical Characteristics (Limits in standard typeface are for T_A = +25°C, bold typeface applies over -40°C to +85°C (Note 6), V_{CC} = 5V, GND = 0V, unless otherwise specified.)

Symbol	Pa	rameter	Conditi	Min	Тур	Мах	Unit	
				10050	—	2	5	
				AS358	_	—	7	
			$V_0 = 1.4V, R_S = 0\Omega,$		_	2	3	1
V _{IO}	Input Offset Voltage		$V_{CC} = 5V \text{ to } 30V$	AS358A		_	5	mV
					_	_	2	1
				AS358B		_	4	_
$\Delta V_{IO} / \Delta T$	Average Temperatu Offset Voltage	re Coefficient of Input	$T_{A} = -40^{\circ}C$ to +85°C		_	7	_	μV/°0
					—	20	200	<u> </u>
BIAS	Input Bias Current		I_{IN} + or I_{IN} -, V_{CM} = 0V			_	200	nA
					—	5	30	
lio	Input Offset Current		$I_{IN} + - I_{IN} -, V_{CM} = 0V$			_	100	nA
VIR	Input Common Mode Voltage Range (Note 7)		V _{CC} = 30V		0	_	V _{CC} - 1.5	V
	Cumply Cumpat		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C,$ $V_{CC} = 30V$	R _L = ∞,	_	0.7	2	
lcc	Supply Current		$T_A = -40^{\circ}C$ to +85°C, $R_L = \infty$, $V_{CC} = 5V$		_	0.5	1.2	- mA
G _V Large Signal Voltage	Coin			85	100		.15	
	Large Signal Voltage	oltage Gain	$V_{CC} = 15V, V_O = 1V$ to $11V, R_L \ge 2k\Omega$		80	_	_	dB
01455	0 N + D -					70		dB
CMRR	Common Mode Reje	tion Ratio	DC, $V_{CM} = 0V$ to $(V_{CC}-1.5)V$		60	_	_	
	Power Supply Rejection Ratio		$V_{CC} = 5V$ to 30V		70	100	_	dB
PSRR					60	_		
CS	Channel Separation		f = 1kHz to 20kHz			-120		dB
			V_{IN} + = 1V, V_{IN} - = 0V, V_{CC} = 15V, V_O = 2V		20	40		
ISOURCE		Source			20	_		- mA
	Output Current		V_{IN} + = 0V, V_{IN} - = 1V,	Vcc = 15V	10	15	_	
	Output Current		$V_{\text{IN}} = 0V, V_{\text{IN}} = 1V, V_{\text{CC}} = 15V,$ $V_{0} = 2V$ $V_{\text{IN}} = 0V, V_{\text{IN}} = 1V, V_{\text{CC}} = 15V,$ $V_{0} = 0.2V$		5	_	_	mA
ISINK		Sink			12	50	_	μA
I _{SC}	Output Short Circuit	Current to Ground	$V_{CC} = 15V$			40	60	mA
-00					26	_	_	+
				$V_{CC} = 30V, R_L = 2k\Omega$				-
V _{OH}					26 27	28		- V
	Output Voltage Swir	g	V_{CC} = 30V, R_L = 10k Ω		27			
Vol					<u> </u>	5	20	<u> </u>
			$V_{CC} = 5V, R_L = 10k\Omega$				30	m∨
θ _{JC}			SO-8			17		
	Thermal Resistance	(Junction to Case)	TSSOP-8		1_	47	·	
	Thermal Resistance (Junction to Case)		MSOP-8		22			
		Thermal Resistance (Junction to Ambient)				115		°C/W
Ο.	Thormal Pasiatonas			SO-8 TSSOP-8				
θ_{JA}	Thermal Resistance					209		
			MSOP-8			160		

7. The input common-mode voltage of either input signal voltage should not be allowed to go negatively by more than 0.3V (at +25°C). The upper end of the common-mode voltage range is V_{CC}-1.5V (at +25°C), but either or both inputs can go to +36V without damages, independent of the magnitude of the V_{CC}.



Performance Characteristics

Input Voltage Range

Input Current



Supply Current



Open Loop Frequency Response





Voltage Gain



Voltage Follower Pulse Response





Performance Characteristics (Cont.)

Voltage Follower Pulse Response (Small Signal)



Output Characteristics: Current Sourcing



Current Limiting



Large Signal Frequency Response



Output Characteristics: Current Sinking





Ordering Information



8. NRND: Not Recommended for New Design

9. For packaging details, go to our website at: https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:



Marking Information

AS358

(1) SO-8



AS358A



(2) MSOP-8





First and Second Lines: Logo and Marking ID Third Line: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: Internal Code

(3) PDIP-8



First Line: Logo and Marking ID Second Line: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: Internal Code



Marking Information (Cont.)

(4) TDIP-8



First Line: Logo and Marking ID Second Line: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: Internal Code

(5) TSSOP-8

AS358/358B



First Line: Logo Second Line: Marking ID Third and Fourth Lines: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: Internal Code



(1) Package Type: PDIP-8





(2) Package Type: TDIP-8





(3) Package Type: SO-8





(4) Package Type: TSSOP-8





(5) Package Type: MSOP-8





Suggested Pad Layout

(1) Package Type: SO-8



Dimensions	Z	G	X	Y	E
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050



Suggested Pad Layout (Cont.)

(2) Package Type: TSSOP-8



Dimensions	Z	G	X	Y	E	E1
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	7.720/0.304	4.160/0.164	0.420/0.017	1.780/0.070	0.650/0.026	1.950/0.077



AS358/358A/358B

Suggested Pad Layout (Cont.)

(3) Package Type: MSOP-8



Dimensions	Z	G	X	Y	E
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	5.500/0.217	2.800/0.110	0.450/0.018	1.350/0.053	0.650/0.026



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